

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I⊳ Max Tc = +25°C
60V	7.3mΩ @ V _{GS} = 10V	95A
000	15mΩ @ VGs = 4.5V	67A

Description and Applications

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$ yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- Power Management Functions
- DC-DC Converters
- Backlighting

Features

- Rated to +175°C—Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low RDS(ON)—Minimizes Power Losses
- Low Qg—Minimizes Switching Losses
- <1.1mm Package Profile—Ideal for Thin Applications</td>
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: PowerDI[®]5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish—Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (€3)
- Weight: 0.097 grams (Approximate)

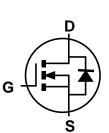
Site 1:

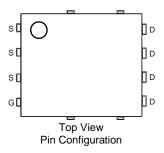


Top View

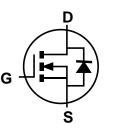
Bottom View

Pin1

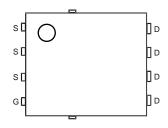




Internal Schematic



Internal Schematic



Top View Pin Configuration

Site 2:

PowerDI5060-8 (SWP) (Type UX)

Top View

Bottom View



Notes:

Ordering Information (Note 4)

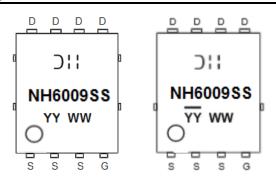
Part Number	Case	Packaging
DMNH6009SPS-13	PowerDI5060-8/ PowerDI5060-8 (SWP) (Type UX)	2500/Tape & Reel

EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



 \bigcirc **! !** = Manufacturer's Marking NH6009SS = Product Type Marking Code YYWW = Date Code Marking YY or \overrightarrow{YY} = Last Two Digits of Year (ex: 20 = 2020) WW = Week Code (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	Vdss	60	V	
Gate-Source Voltage	Vgss	±20	V	
Continuous Drain Current (Note 7) V _{GS} = 10V	T _C = +25°C T _C = +100°C	Ъ	95 67	А
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%)		I _{DM}	380	A
Maximum Continuous Body Diode Forward Current (Note 7)		ls	95	А
Pulsed Source Current (380µs Pulse, Duty Cycle = 1%)		Ism	380	А
Avalanche Current, L = 0.1mH (Note 8)	I _{AS}	56	А	
Avalanche Energy, L = 0.1mH (Note 8)		Eas	226	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	1.6	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	95	°C/W
Total Power Dissipation (Note 6)		PD	3.3	W
Thermal Resistance, Junction to Ambient (Note 6) Steady State		R _{0JA}	46	00000
Thermal Resistance, Junction to Case (Note 7)		Rejc	1.5	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes: 5. Device mounted on FR-4 PCB, with minimum recommended pad layout, single sided.

6. Device mounted on FR-4 substrate PCB, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

7. Thermal resistance from junction to soldering point (on the exposed drain pad).

8. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.



Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

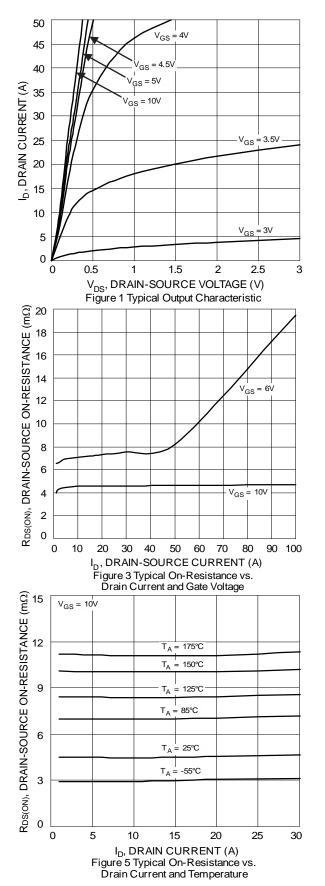
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)		-				-	
Drain-Source Breakdown Voltage	BVDSS	60	_	—	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current, TJ = +25°C	IDSS	_	_	1	μA	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	VGS(TH)	1	2	3	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	RDS(ON)		4.6	7.3	mΩ	Vgs = 10V, ID = 50A	
Static Drain-Source On-Resistance	Rds(on)		7.1	15	mΩ	V _{GS} = 4.5V, I _D = 25A	
Diode Forward Voltage	V _{SD}	_	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 1.7A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss		1882	-	pF	V _{DS} = 30V, V _{GS} = 0V, f = 1MHz	
Output Capacitance	Coss		374	—	pF		
Reverse Transfer Capacitance	Crss		111	-	pF		
Gate Resistance	Rg	_	2.1	—	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg		18.5	-	nC		
Total Gate Charge (V _{GS} = 10V)	Qg	—	37.3	—	nC		
Gate-Source Charge	Qgs	_	5.0	—	nC	VDS = 30V, ID = 25A	
Gate-Drain Charge	Q _{gd}	—	11.2	—	nC	7	
Turn-On Delay Time	t _{D(ON)}	_	5.7	—	ns		
Turn-On Rise Time	tR	_	7.5	_	ns	$V_{GS} = 10V, V_{DS} = 30V,$ $R_g = 3\Omega, I_D = 25A$	
Turn-Off Delay Time	tD(OFF)	_	16.9	_	ns		
Turn-Off Fall Time	tF		6.3	_	ns	7	
Body Diode Reverse Recovery Time	trr	—	32	—	ns		
Body Diode Reverse Recovery Charge	Q _{RR}	—	30	—	nC	– I _F = 25A, di/dt = 100A/μs	

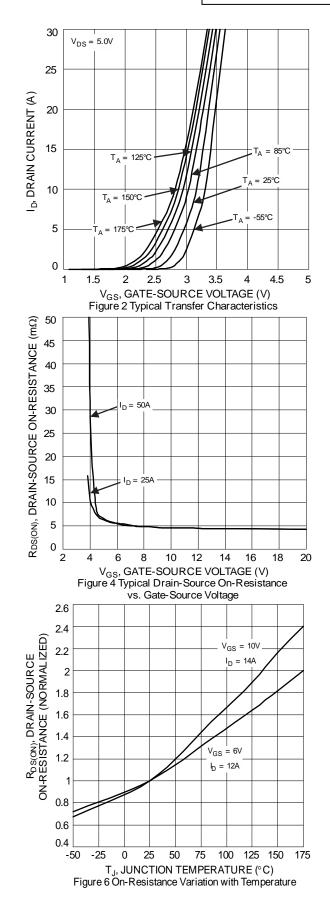
 Notes:
 9. Short duration pulse test used to minimize self-heating effect.

 10. Guaranteed by design. Not subject to product testing.

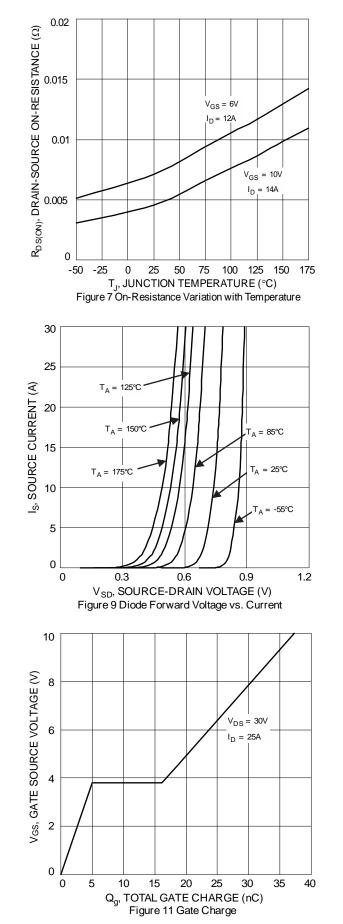


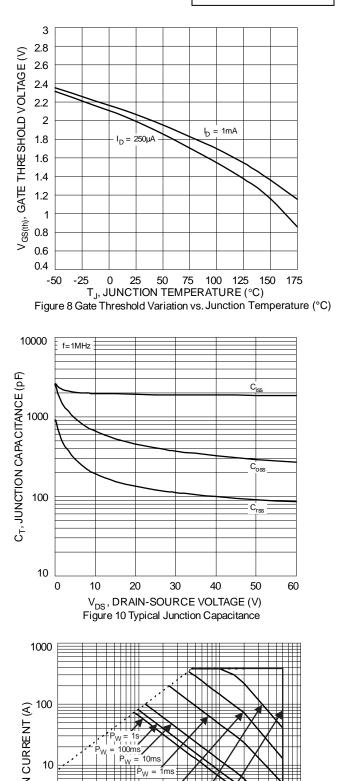
DMNH6009SPS

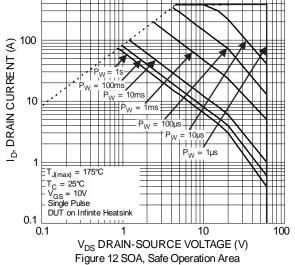




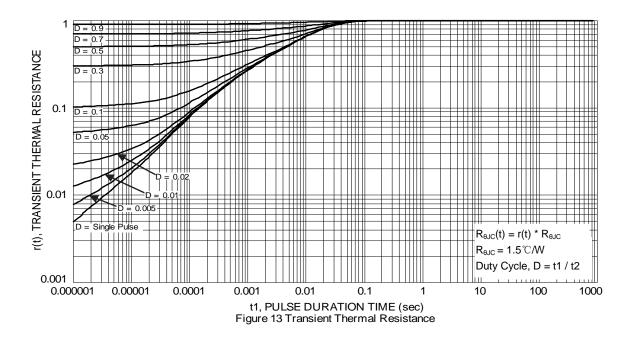














Package Outline Dimensions

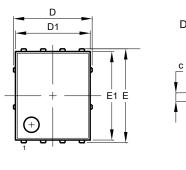
Please see http://www.diodes.com/package-outlines.html for the latest version.

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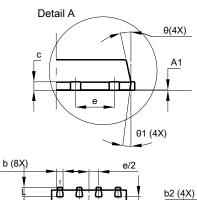
E3 E2

G

Site1:



Detail A



Dβ

 $\overline{D2}$

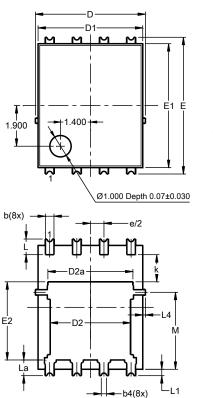
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L1

PowerDI5060-8

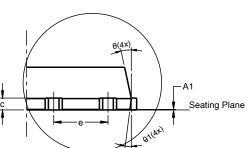
	PowerDI5060-8				
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	_		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D		5.15 BSC			
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
E	(6.15 BSC	;		
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е		1.27 BSC	;		
G	0.51	0.71	0.61		
K	0.51		—		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
Al	All Dimensions in mm				

Site2:

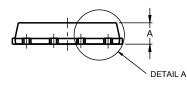


PowerDI5060-8 (SWP) (Type UX)

b3 (4X)



DETAIL A	



PowerDI5060-8 (SWP) (Type UX)				
Dim	Min Max Typ			
Α	0.90	1.10	1.00	
A1	0	0.05		
b	0.30	0.50	0.41	
b2	0.20	0.35	0.25	
b4	().25REF	-	
C	0.230	0.330	0.277	
D	5	.15 BS0	2	
D1	4.70	5.10	4.90	
D2	3.56	3.96	3.76	
D2a	3.78	4.18	3.98	
ш	6.40 BSC			
E1	5.60	6.00	5.80	
E2	3.46	3.86	3.66	
E2a	4.195	4.595	4.395	
е	1	.27BSC)	
k	1.05			
L	0.635	0.835	0.735	
La	0.635	0.835	0.735	
L1	0.200	0.400	0.300	
L1a	0	.050RE	F	
L4	0.025	0.225	0.125	
Μ	3.205	4.005	3.605	
θ	10°	12°	11°	
θ1	6°	8°	7°	
All	Dimensi	ions in	mm	

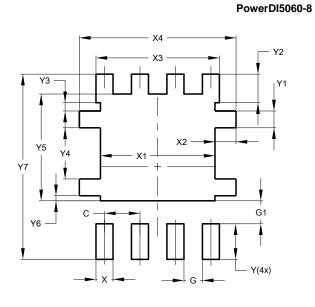
DMNH6009SPS Document number: DS41482 Rev. 3 - 2



Suggested Pad Layout

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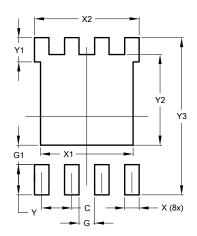
Site1:



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

Site2:

PowerDI5060-8 (SWP) (Type UX)



Dimensions	Value (in mm)	
С	1.270	
G	0.660	
G1	0.820	
Х	0.610	
X1	4.100	
X2	4.420	
Y	1.270	
Y1	1.020	
Y2	3.810	
Y3	6.610	



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